TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

# TA8164P

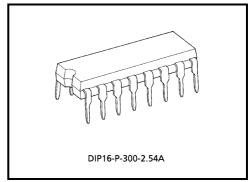
#### 3V Monaural Radio IC

The TA8164P is AM / FM tuner (FM F / E + AM / FM IF) IC, which is designed for AM / FM monaural radio. Combining with the TA7368P (mono PW IC), a suitable monaural AM / FM radio system is able to be constituted.

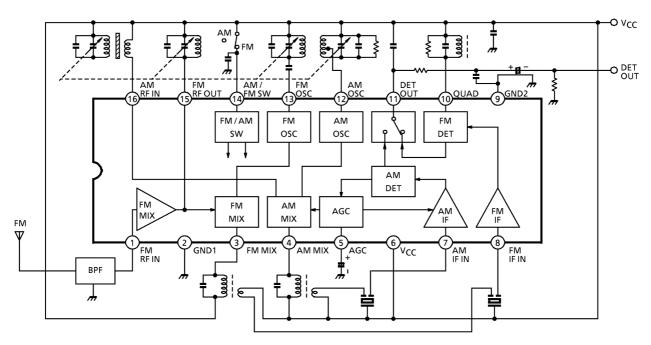
### Features

- Common output for AM / FM
- Switch over between AM / FM mode is possible with one-wake switch.
- Operating supply voltage range : V<sub>CC</sub> (opr) = 1.8~7V (Ta = 25°C)

### **Block Diagram**



Weight: 1.00g (typ.)



### **Explanation Of Terminal**

Pin No.	Symbol	Internal Circuit	DC Volt (at no AM	tage (V) signal) FM
1	FM-RF in	FM-RF OUT (15) (1) (2) (1) (2) (1) (2) (1) (2) (1) (1) (1) (1) (1) (1) (1) (1) (1) (1	0	0.7
2	GND1 (GND for AM RF, OSC, MIX, FM RF, OSC, MIX)	_	0	0
3	FM MIX	AM/FM SW 14	3.0	3.0
4	AM MIX	V <sub>CC</sub> 6 4 4 4 4 4 4 4 4 4 4 5 5 5 6 5 7 6 7 7 7 7 7 7 7 7 7 7 7 7 7	3.0	3.0
5	AGC (AM AGC)	IF AGC	0	0
6	V <sub>CC</sub>	—	3.0	3.0
7	AM IF in	V <sub>CC</sub> (6) (7) (7) (7) (7) (7) (7) (7) (7) (7) (7	3.0	3.0
8	FM IF in		3.0	3.0

Pin No.	Symbol	Internal Circuit	DC Volt (at no	age (V) signal) FM
9	GND2 (GND for AM IF and FM IF)		AM 0	ГМ 0
10	QUAD (FM QUAD, Detector)		3.0	3.0
11	DET out	V <sub>CC</sub> GND2 (B) (B) (C) (C) (C) (C) (C) (C) (C) (C	1.4	1.4
12	AM OSC	V <sub>CC</sub> 6 MIX GND1 2 MIX	3.0	3.0
13	FM OSC	AM / FM SW 14 13 MIX - II GND1 2	3.0	3.0
14	AM / FM SW Pin (14) V <sub>CC</sub> →FM Pin (14) open →AM	AM IF FM IF GND2 9	_	3.0
15	FM RF out	Cf. Pin (1)	3.0	3.0
16	AM RF in	V <sub>CC</sub> 6 (6) (6) (6) (7) (7) (7) (7) (7) (7) (7) (7) (7) (7	3.0	3.0

### Maximum Ratings (Ta = 25°C)

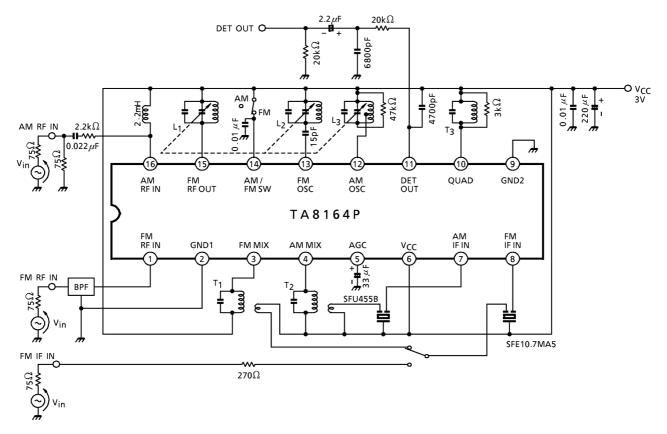
Characteristic	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	8	V
Power dissipation	P <sub>D</sub> (Note)	750	mW
Operating temperature	Topr	-25~75	°C
Storage temperature	Tstg	-55~150	°C

(Note) Derated above Ta =  $25^{\circ}$ C in the proportion of 6mW / °C.

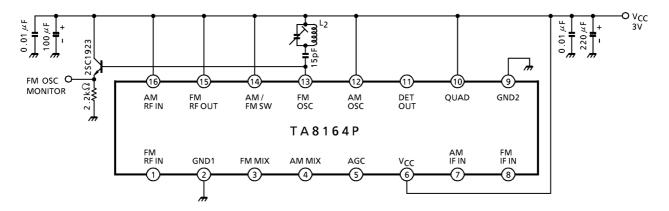
#### Electrical Characteristics Unless Otherwise Specified, Ta = 25°C, V<sub>CC</sub> = 3V, F / E: f = 98MHz, f<sub>m</sub> = 1kHz FM IF: f = 10.7MHz, $\Delta f$ = ±22.5kHz, f<sub>m</sub> = 1kHz AM: f = 1MHz, MOD = 30%, f<sub>m</sub> = 1kHz

Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit	
Supply current		I <sub>CC</sub> (FM)	1	FM mode V <sub>in</sub> = 0	_	10.5	15.5	mA	
Suppi	ycurrent	I <sub>CC</sub> (AM)	1	AM mode V <sub>in</sub> = 0		4.5	7.0	ШA	
	Input limiting voltage	V <sub>in (lim)</sub>	1	-3dB limiting point		12	_	dBµV EMF	
FM F/E	Quiescent sensitivity	QS	1	S / N = 30dB		12	_	dBµV EMF	
· / L	Local OSC voltage	V <sub>OSC</sub>	2	f <sub>OSC</sub> = 108MHz	150	205	280	mV <sub>rms</sub>	
	Local OSC stop supply voltage	V <sub>stop</sub> (FM)	2	V <sub>in</sub> = 0	_	1.2	_	V	
	Input limiting voltage	V <sub>in (lim)</sub> IF	1	-3dB limiting point	44	50	56	dBµV EMF	
FM	Recovered output voltage V <sub>OD</sub> 1 V <sub>in</sub> = 80dBµV EMF		V <sub>in</sub> = 80dBµV EMF	20	35	55	mV <sub>rms</sub>		
IF	Signal to noise ratio	S / N	1	V <sub>in</sub> = 80dBµV EMF		62	-	dB	
	Total harmonic distortion	THD 1		V <sub>in</sub> = 80dBµV EMF	_	0.4	_	%	
	AM rejection ratio	ejection ratio AMR 1 V <sub>in</sub> = 80dBµV EMF			33		dB		
	Gain	GV	1	V <sub>in</sub> = 30dBµV EMF	15	30	45	mV <sub>rms</sub>	
	Recovered output VOI voltage		1	V <sub>in</sub> = 60dBµV EMF	20	35	55	mV <sub>rms</sub>	
AM	Signal to noise ratio S / N		1	V <sub>in</sub> = 60dBµV EMF		43	—	dB	
	Total harmonic distortion	THD	1	V <sub>in</sub> = 60dBµV EMF	_	1.0	_	%	
	Local OSC stop supply voltage	V <sub>stop</sub> (AM)	1	V <sub>in</sub> = 0	_	1.6	_	V	

### **Test Circuit 1**



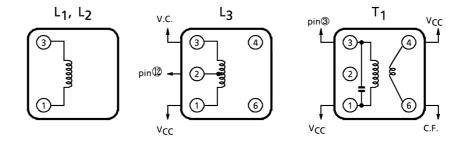
### **Test Circuit 2**

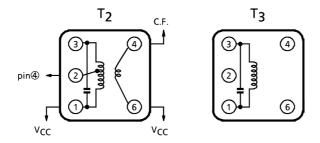


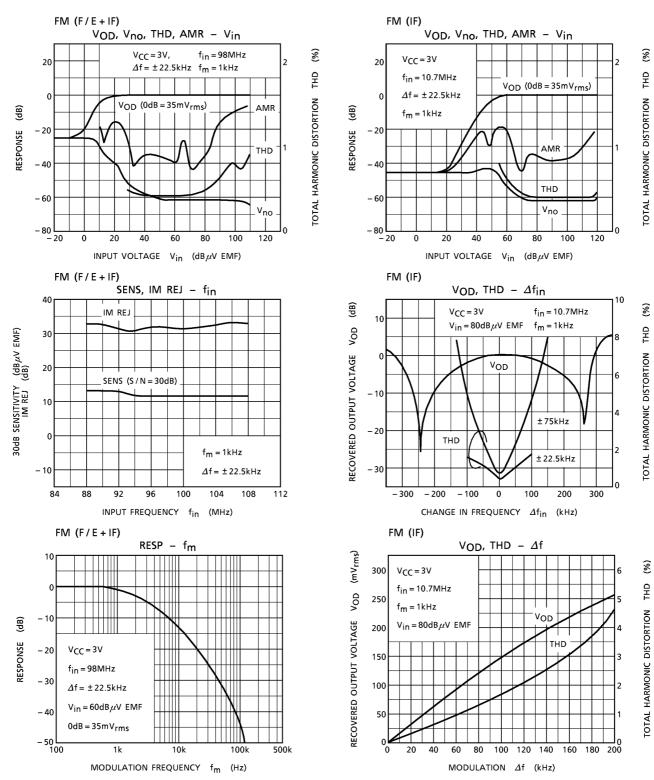
### Coil Data

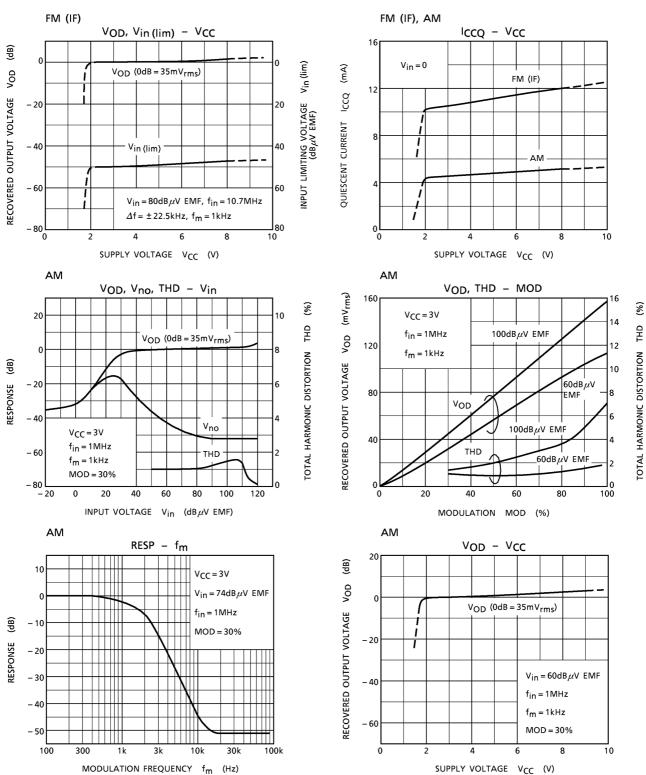
	f L Co		Co		Turns				Wire	D-f		
Coil No.	(Hz)	(µH)	(pF)	Q <sub>o</sub>	1–2	2–3	1–3	1–4	4–6	(mmø)	Ref.	
L <sub>1</sub> FM RF	100M		_	100		_	_	$2\frac{1}{4}$	—	0.5UEW	(S) 0258-000-021	
L <sub>2</sub> FM OSC	100M	_	_	100		_	$1\frac{3}{4}$	_	_	0.5UEW	(S) 0258–000–020	
L <sub>3</sub> AM OSC	796k	268	_	125	14	86	-	—	_	0.06UEW	(S) 2157–2239–213A	
T <sub>1</sub> FM MIX	10.7M		75	100		—	13	—	2	0.1UEW	(S) 2153–414–041A	
T <sub>2</sub> AM MIX	455k		330	100	65	45	110	_	6	0.08UEW	(S) 4140–1289–311	
$T_3$ FM DET	10.7M		100	95	_	_	12	_	_	0.12UEW	(S) 2153-4095-189	

(S): Sumida electric co., ltd.





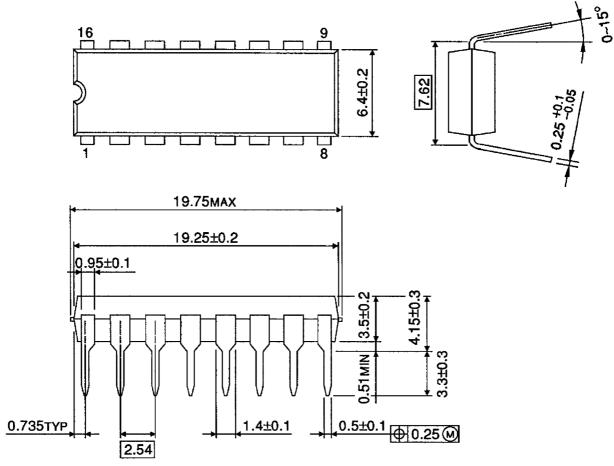




### Package Dimensions

DIP16-P-300-2.54A

Unit : mm



Weight: 1.0g (typ.)

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Handbook" etc..

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